

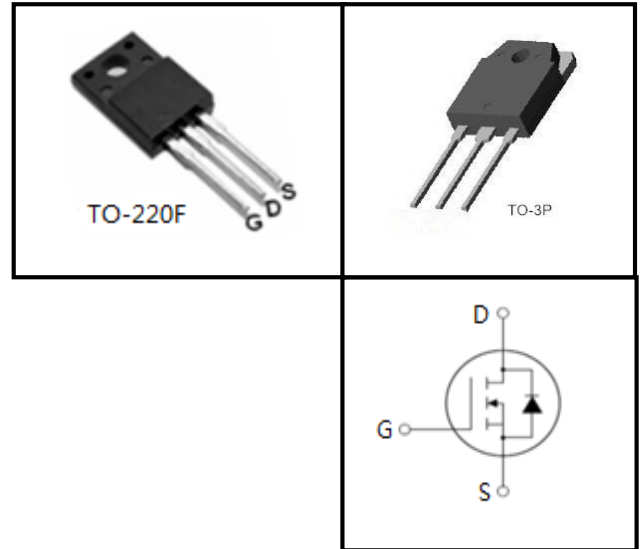
700V N-Channel MOSFET

FEATURES

- Fast switching
- 100% avalanche tested
- Improved dv/dt capability

APPLICATIONS

- Switch Mode Power Supply (SMPS)
- Uninterruptible Power Supply (UPS)
- Power Factor Correction (PFC)



Device Marking and Package Information

Device	Package	Marking
CS18N70F	TO-220F	CS18N70F
CS18N70V	TO-3P	CS18N70V

Absolute Maximum Ratings $T_C = 25^\circ\text{C}$, unless otherwise noted

Parameter	Symbol	Value		Unit
		TO-220F	TO-3P	
Drain-Source Voltage ($V_{GS} = 0\text{V}$)	V_{DSS}	700		V
Continuous Drain Current	I_D	18		A
Pulsed Drain Current (note1)	I_{DM}	72		A
Gate-Source Voltage	V_{GSS}	± 30		V
Single Pulse Avalanche Energy (note2)	E_{AS}	352.8		mJ
Avalanche Current (note1)	I_{AR}	8.4		A
Repetitive Avalanche Energy (note1)	E_{AR}	211.68		mJ
Power Dissipation ($T_C = 25^\circ\text{C}$)	P_D	25	70	W
Operating Junction and Storage Temperature Range	T_J, T_{stg}	-55~+150		$^\circ\text{C}$

Thermal Resistance

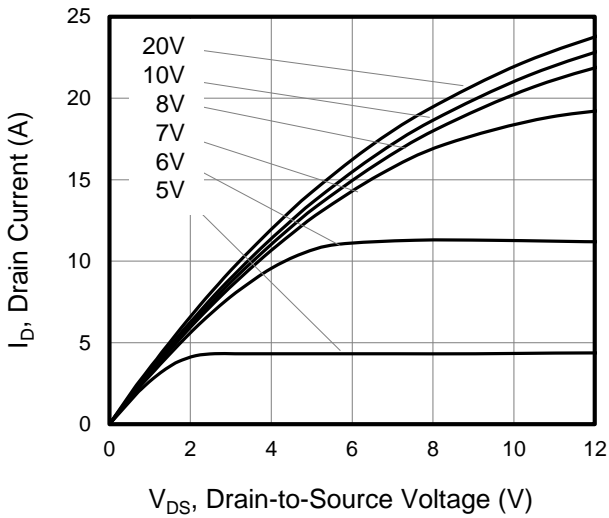
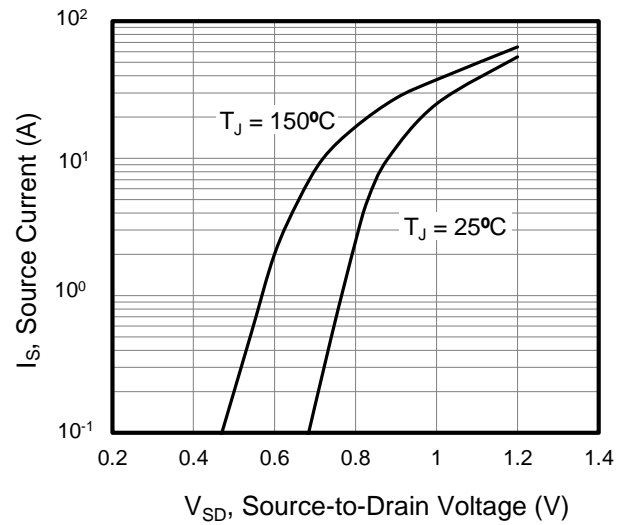
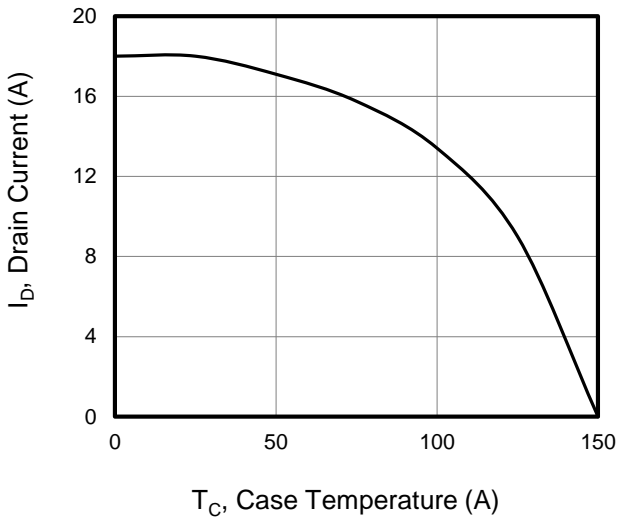
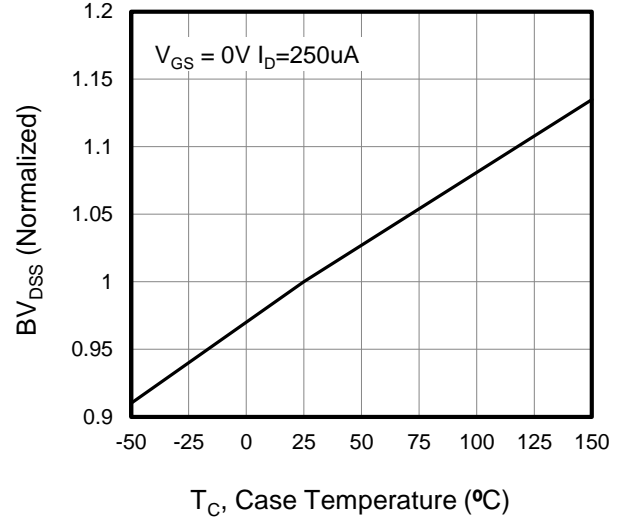
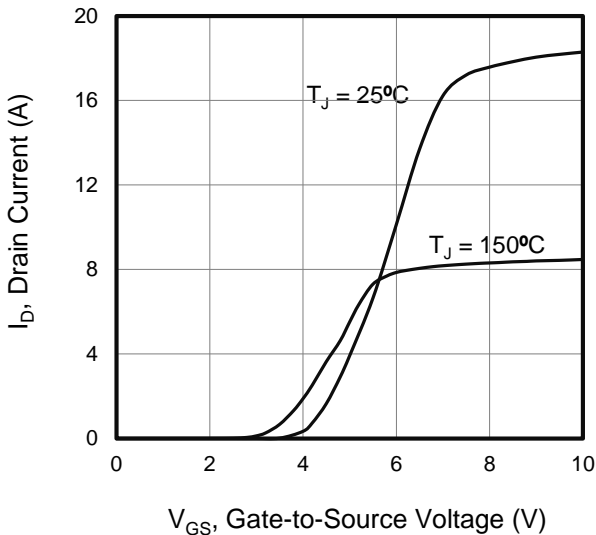
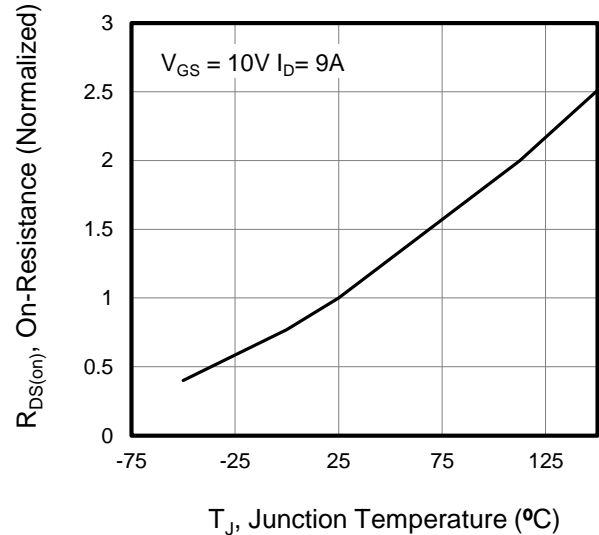
Parameter	Symbol	Value		Unit
		TO-220F	TO-3P	
Thermal Resistance, Junction-to-Case	R_{thJC}	5	1.78	K/W
Thermal Resistance, Junction-to-Ambient	R_{thJA}	62.5	60	

Specifications $T_J = 25^\circ\text{C}$, unless otherwise noted						
Parameter	Symbol	Test Conditions	Value			Unit
			Min.	Typ.	Max.	
Static						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu\text{A}$	700	--	--	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 700V, V_{GS} = 0V, T_J = 25^\circ\text{C}$	--	--	1	μA
Gate-Source Leakage	I_{GSS}	$V_{GS} = \pm 30V$	--	--	± 100	nA
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu\text{A}$	3.0	--	4.0	V
Drain-Source On-Resistance (Note3)	$R_{DS(on)}$	$V_{GS} = 10V, I_D = 9A$	--	0.45	0.55	Ω
Dynamic						
Input Capacitance	C_{iss}	$V_{GS} = 0V,$ $V_{DS} = 25V,$ $f = 1.0\text{MHz}$	--	2589	--	pF
Output Capacitance	C_{oss}		--	233.5	--	
Reverse Transfer Capacitance	C_{rss}		--	28.6	--	
Total Gate Charge	Q_g	$V_{DD} = 560V, I_D = 18A,$ $V_{GS} = 10V$	--	73.5	--	nC
Gate-Source Charge	Q_{gs}		--	10.2	--	
Gate-Drain Charge	Q_{gd}		--	35	--	
Turn-on Delay Time	$t_{d(on)}$	$V_{DD} = 350V, I_D = 18A,$ $R_G = 25\Omega$	--	54	--	ns
Turn-on Rise Time	t_r		--	25.7	--	
Turn-off Delay Time	$t_{d(off)}$		--	334	--	
Turn-off Fall Time	t_f		--	57.7	--	
Drain-Source Body Diode Characteristics						
Continuous Body Diode Current	I_S	$T_C = 25^\circ\text{C}$	--	--	18	A
Pulsed Diode Forward Current	I_{SM}		--	--	72	
Body Diode Voltage	V_{SD}	$T_J = 25^\circ\text{C}, I_{SD} = 9A, V_{GS} = 0V$	--	--	1.4	V
Reverse Recovery Time	t_{rr}	$V_{GS} = 0V, I_S = 18A,$ $di_F/dt = 100A/\mu\text{s}$	--	770	--	ns
Reverse Recovery Charge	Q_{rr}		--	5.4	--	μC

Notes

1. Repetitive Rating: Pulse width limited by maximum junction temperature
2. $L = 10.0\text{mH}, V_{DD} = 50V, R_G = 25\Omega$, Starting $T_J = 25^\circ\text{C}$
3. Pulse Test: Pulse width $\leq 300\mu\text{s}$, Duty Cycle $\leq 1\%$

Typical Characteristics $T_J = 25^\circ\text{C}$, unless otherwise noted

Figure 1. Output Characteristics ($T_J = 25^\circ\text{C}$)

Figure 2. Body Diode Forward Voltage

Figure 3. Drain Current vs. Temperature

Figure 4. BV_{DSS} Variation vs. Temperature

Figure 5. Transfer Characteristics

Figure 6. On-Resistance vs. Temperature


Typical Characteristics $T_J = 25^\circ\text{C}$, unless otherwise noted

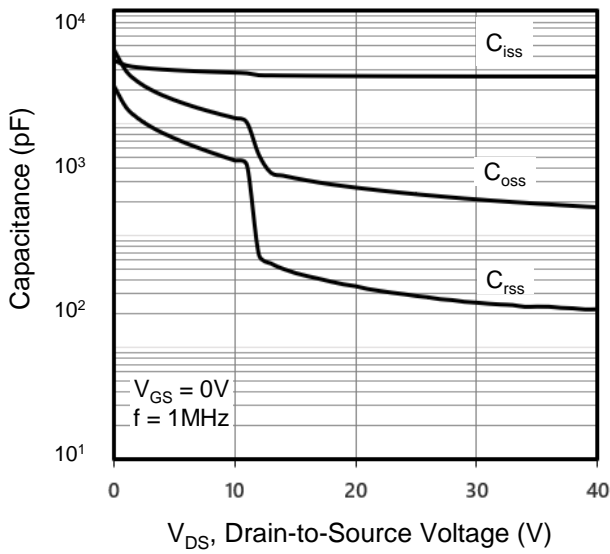
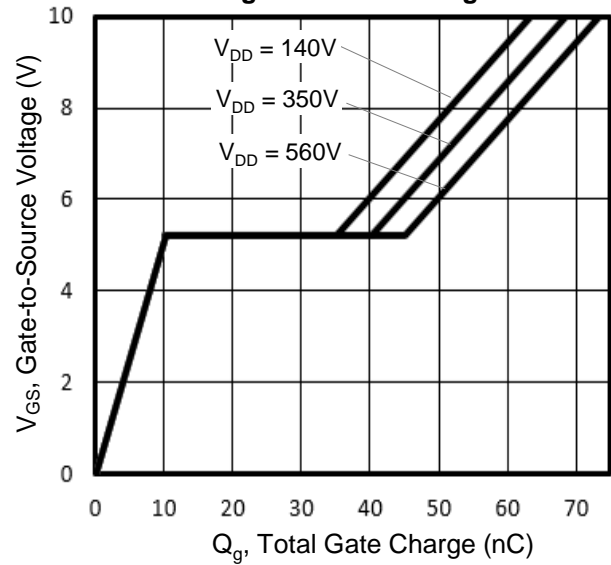
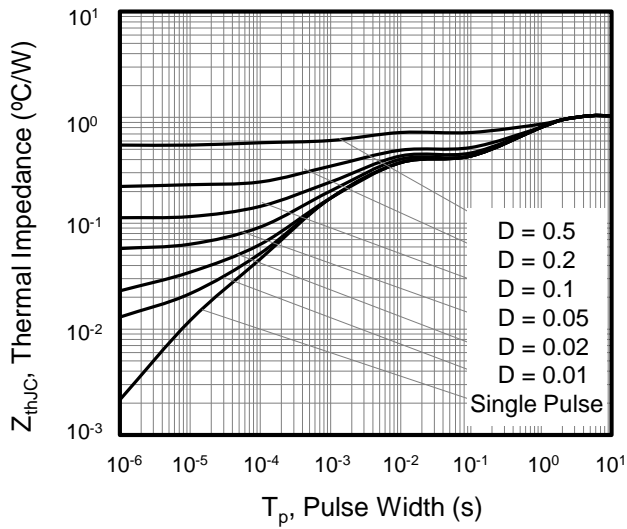
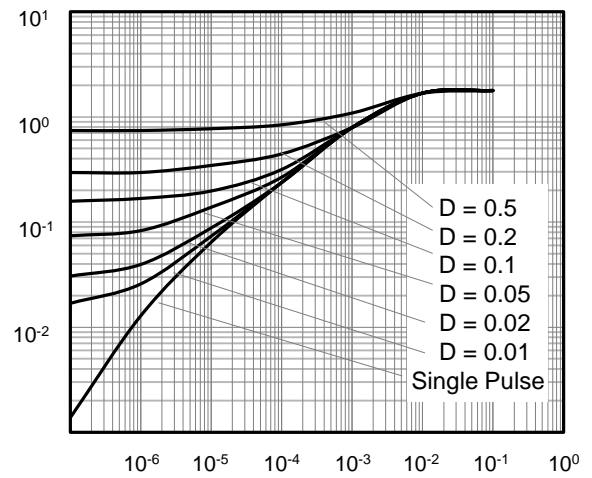
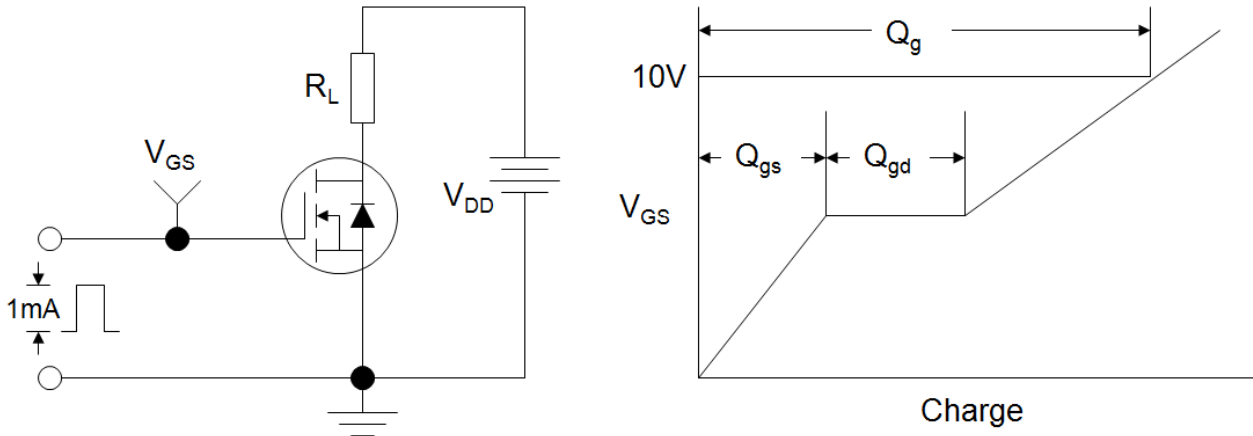
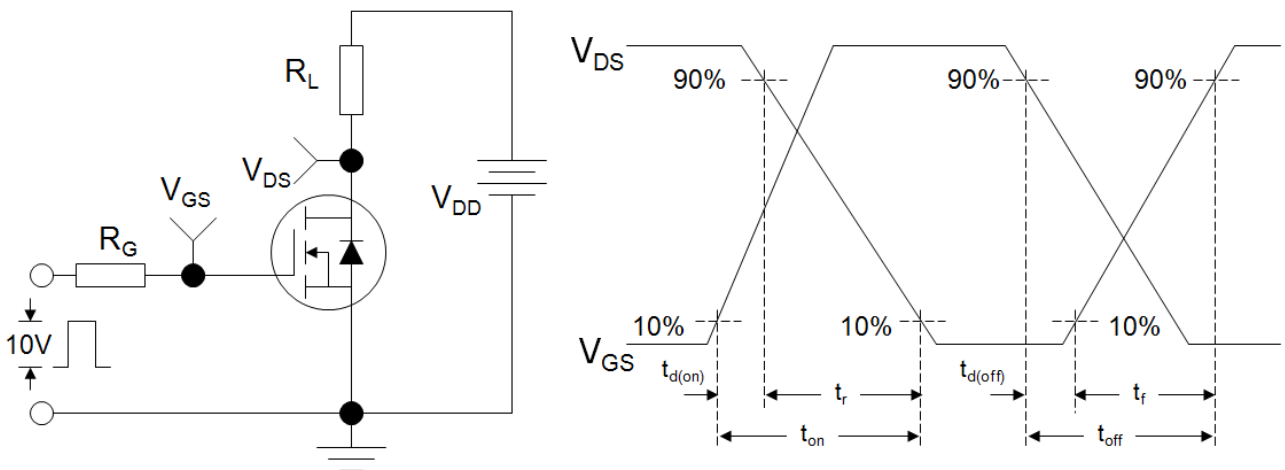
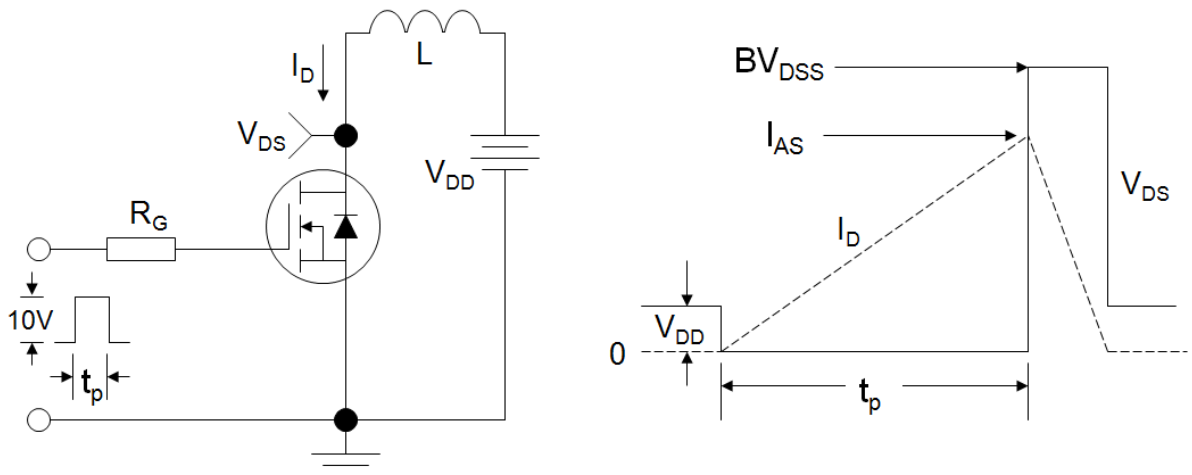
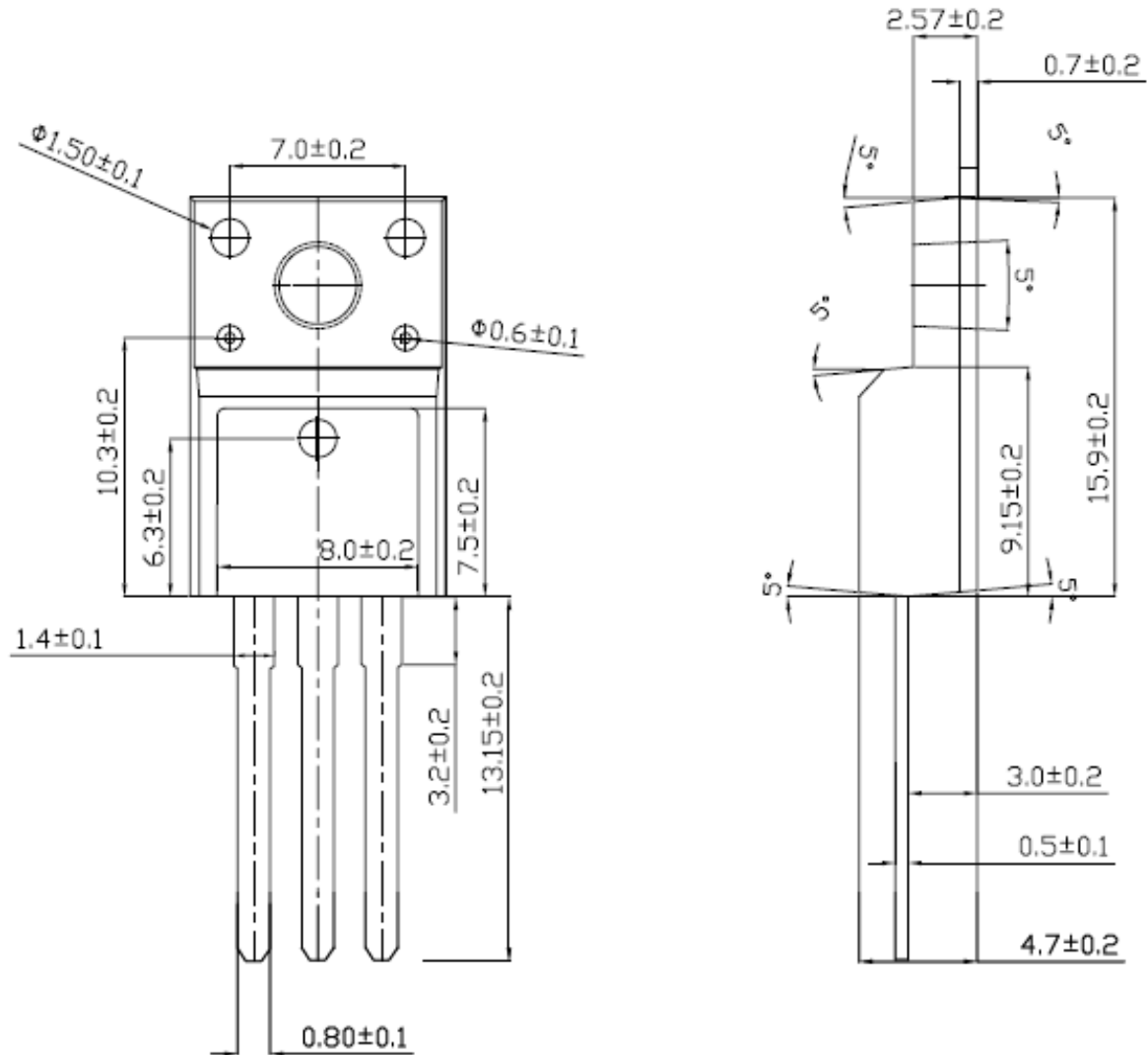
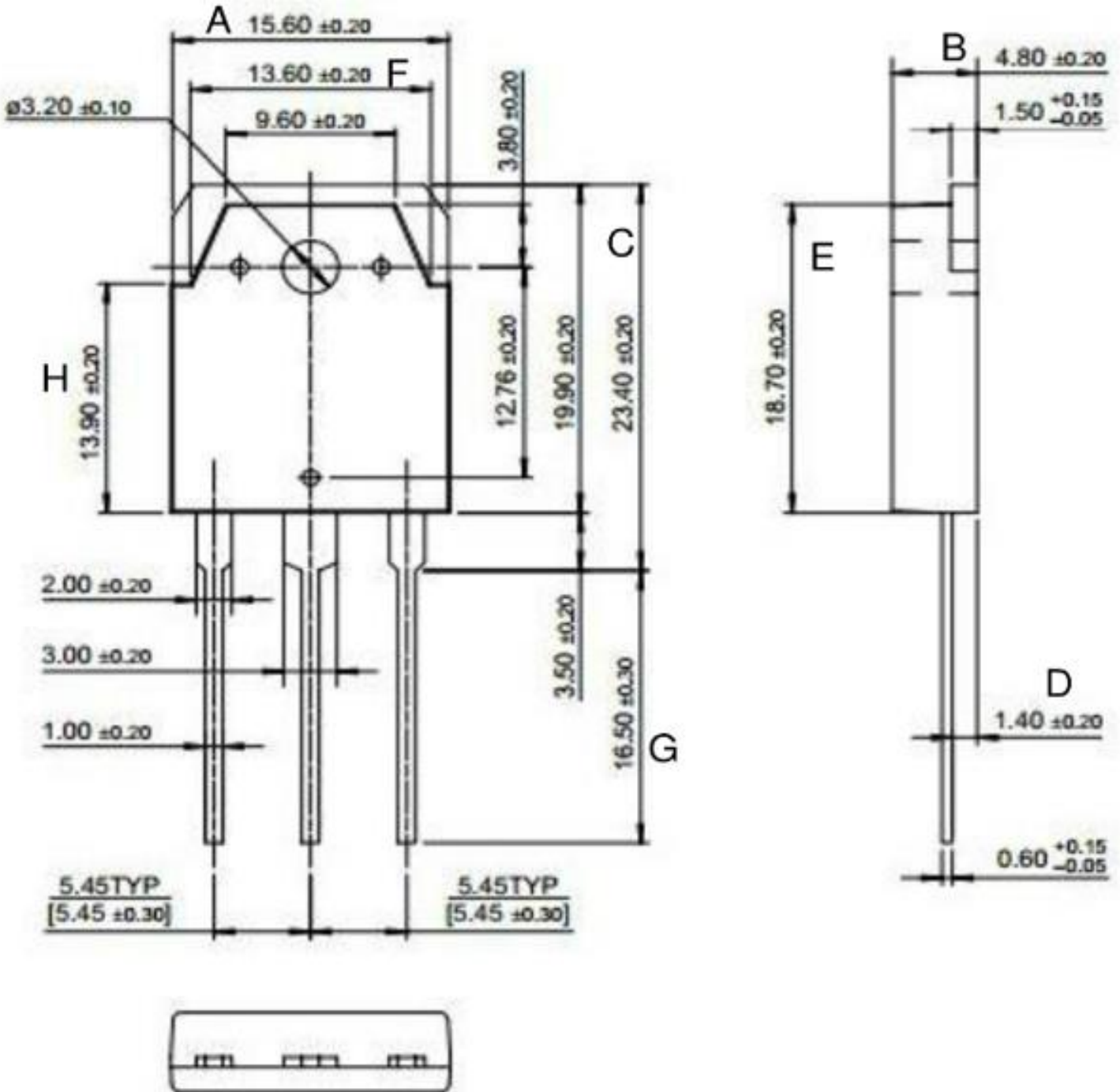
Figure 7. Capacitance

Figure 8. Gate Charge

Figure 9. Transient Thermal Impedance TO-220F

Figure 10. Transient Thermal Impedance TO-3P


Figure A: Gate Charge Test Circuit and Waveform

Figure B: Resistive Switching Test Circuit and Waveform

Figure C: Unclamped Inductive Switching Test Circuit and Waveform


TO-220F


TO-3P


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